## NSN 5961-00-929-2605

No Fiig: A110a0

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-929-2605 **Inclosure Material:** Metal **Overall Length:** Between 0.240 inches and 0.260 inches **Terminal Length:** 1.500 inches **Overall Diameter:** Between 0.335 inches and 0.370 inches **Internal Configuration:** Junction contact **Mounting Method: Terminal Terminal Circle Diameter:** 0.200 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 50.0 reverse voltage, dc and 50.0 on voltage, forward voltage drop, dc **Current Rating Per Characteristic:** 1.00 amperes forward current, average absolute and 2.00 amperes source cutoff current minor **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Special Features:** Junction pattern arrangement: pnpn **Test Data Document:** 82577-925275 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:** Demilitarization: